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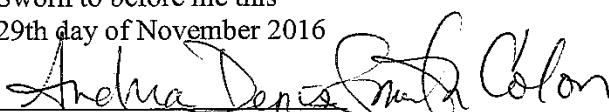
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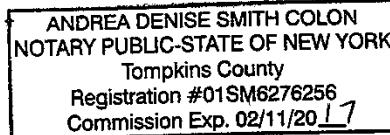
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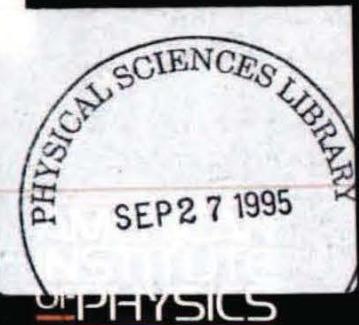
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- 1914 Intensity-dependent energy and line shape variation of donor-acceptor-pair bands in ZnSe:N at different compensation levels P. Bäume, J. Gutowski, D. Wiesmann, R. Heitz, A. Hoffmann, E. Kurtz, D. Hommel, G. Landwehr
- SUPERCONDUCTORS**
- 1917 Extended function of a high- $T_c$  transition edge bolometer on a micromachined Si membrane H. Neff, J. Laukemper, G. Hefle, M. Burnus, T. Heidenblut, W. Michalke, E. Steinbeiss
- 1920 Deposition of high quality  $\text{YBa}_2\text{Cu}_3\text{O}_{7-x}$  films on ultrathin ( $12 \mu\text{m}$  thick) sapphire substrates for infrared detector applications A. Piqué, K. S. Harshavardhan, J. Moses, M. Mathur, T. Venkatesan, J. C. Brasunas, B. Lakew
- 1923 Generation of 24.0 T at 4.2 K and 23.4 T at 27 K with a high-temperature superconductor coil in a 22.54 T background field K. Ohkura, K. Sato, M. Ueyama, Jun Fujikami, Y. Iwasa
- 1926 Biomagnetic measurements using low-noise integrated SQUID magnetometers operating in liquid nitrogen M. S. Dilorio, K.-Y. Yang, S. Yoshizumi
- 1929 Correlation of critical current and resistance fluctuations in bicrystal grain boundary Josephson junctions A. Marx, U. Fath, L. Alff, R. Gross
- 1932 Determination of pinning strength of  $\text{YBa}_2\text{Cu}_3\text{O}_{7-\delta}$  from magnetic stiffness measurements Beate Lehndorff, Hans-Gerd Kürschner, Bernhard Lücke
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- 1941 Ferroelectric phase transition temperatures of  $\text{KTiOPO}_4$  crystals grown from self-fluxes N. Angert, M. Tseitlin, E. Yashchin, M. Roth
- COMMENTS**
- 1944 Comment on "Phase transformation of cobalt induced by ball milling" [Appl. Phys. Lett. 66, 308 (1995)] G. Mazzone
- 1945 Response to "Comment on 'Phase transformation of cobalt induced by ball milling'" [Appl. Phys. Lett. 67, 1944 (1995)] J. Y. Huang, Y. K. Wu, H. Q. Ye
- 1947 CUMULATIVE AUTHOR INDEX

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